









	<h2 style="color: red;">SPP06N80C3</h2>	
	Hersteller-Teilenummer:	SPP06N80C3
	Hersteller / Marke:	International Rectifier (Infineon Technologies)
	Teil der Beschreibung:	SPP06N80C3 Infineon Technologies
Datenblätter:	 SPP06N80C3.pdf	
RoHs Status:	Bleifrei / RoHS-konform	
Lagerzustand:	New original, 21005 pcs Stock Available.	
Liefern von:	Hong Kong	
Versandweg:	DHL/Fedex/TNT/UPS/EMS	
<p>Image may be representation. See specs for product details.</p>		

Spezifikationen

Teilenummer	SPP06N80C3
Hersteller	International Rectifier (Infineon Technologies)
Beschreibung	SPP06N80C3 Infineon Technologies
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	21005 pcs Stock
Serie	CoolMOS™
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3
Supplier Device-Gehäuse	PG-TO-220-3
Verlustleistung (max)	83W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	800V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	6A (Tc)
Rds On (Max) @ Id, Vgs	900 mOhm @ 3.8A, 10V
VGS (th) (Max) @ Id	3.9V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	41nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	785pF @ 100V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±20V
Verpackung	Tube

SPP06N80C3 ist neu im Original, Suche SPP06N80C3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SPP06N80C3 International Rectifier (Infineon Technologies) mit Garantie und Vertrauen. Anfrage SPP06N80C3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SPP07N60C2 Original SPP07N60C2 Original</p>	 <p>SPP06N60C3_07 VB SPP06N60C3_07 VB</p>	 <p>SPP06N80C3XK International Rectifier (Infineon Technologies) MOSFET N-CH 800V 6A TO-220AB</p>	 <p>SPP06N60C3XKSA1 International Rectifier (Infineon Technologies) LOW POWER_LEGACY</p>
 <p>SPP06N60C3HKSA1 International Rectifier (Infineon Technologies) MOSFET N-CH 650V 6.2A TO-220</p>	 <p>SPP04N80C3XKSA1 International Rectifier (Infineon Technologies) MOSFET N-CH 800V 4A TO-220AB</p>	 <p>SPP072N10N3G inf SPP072N10N3G inf</p>	 <p>SPP06N80C3XKSA1 International Rectifier (Infineon Technologies) MOSFET N-CH 800V 6A TO-220AB</p>

heiße Teile

Mehr

SPP-5K550	SPP02N60C3	SPP02N60S5	SPP03N60C3	SPP03N60S5
SPP04N50C3	SPP04N60C2	SPP04N60C3	SPP04N60S5	SPP04N80C3
SPP06N60C3	SPP06N60C3_07	SPP07N60C2	SPP07N60C3	SPP07N60CFD
SPP07N60S5	SPP07N65C3	SPP08N50C3	SPP08N50C3HKSA1	SPP08N80C3
SPP08P06P	SPP08P06PG	SPP08P06PH	SPP100N03S2-03	SPP100N03S203
SPP100N03S2L-03	SPP100N03S2L03	SPP100N03S3-03	SPP100N04S2-04	SPP100N04S2-04.
SPP100N04S2L-03	SPP100N06S2-05	SPP100N06S2L-05	SPP100N08S2L-07	SPP1013S52RG
SPP1013S52RGB	SPP1015S52RGB	SPP1021S56RG	SPP1023S56RG	SPP1071S72RGB
SPP1073S72RGB	SPP10N10	SPP10N10L	SPP10N80C3	SPP11N60C2
SPP11N60C3	SPP11N60CFD	SPP11N60S5	SPP11N65C3	SPP11N65S5

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